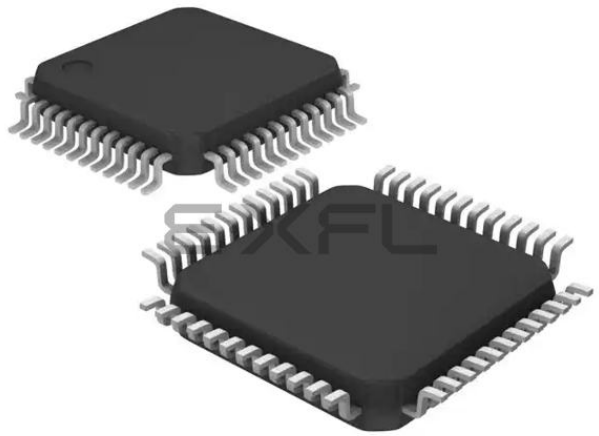

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What is "Embedded - Microcontrollers"?

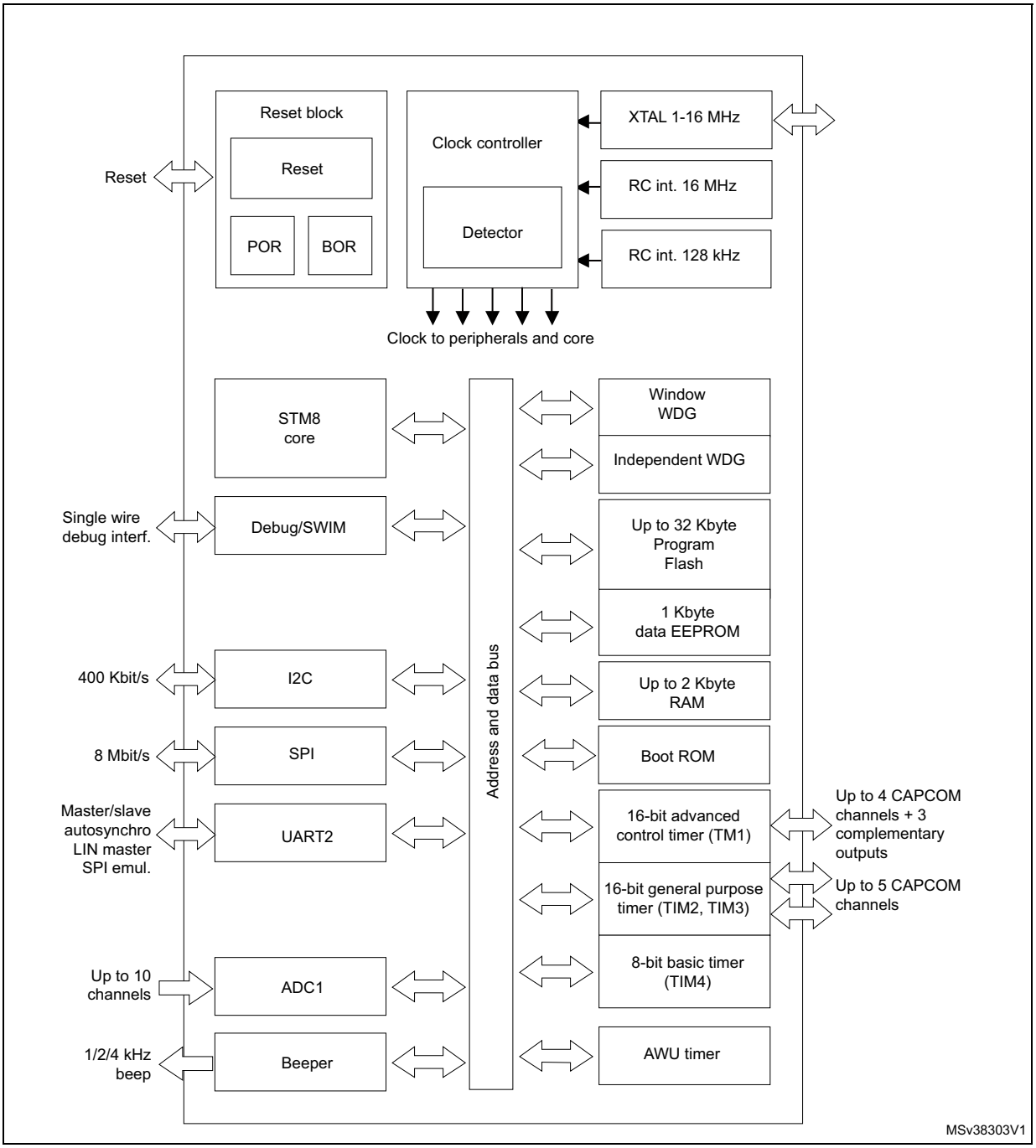
"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	STM8
Core Size	8-Bit
Speed	16MHz
Connectivity	I²C, IrDA, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	38
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	1K x 8
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	2.95V ~ 5.5V
Data Converters	A/D 10x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	-
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm8s105c6t6

3 Block diagram

Figure 1. STM8S105x4/6 block diagram



4 Product overview

The following section provides an overview of the basic features of the device functional modules and peripherals.

For more detailed information please refer to the corresponding family reference manual (RM0016).

4.1 Central processing unit STM8

The 8-bit STM8 core is designed for code efficiency and performance.

It contains 6 internal registers which are directly addressable in each execution context, 20 addressing modes including indexed indirect and relative addressing and 80 instructions.

Architecture and registers

- Harvard architecture,
- 3-stage pipeline,
- 32-bit wide program memory bus - single cycle fetching for most instructions,
- X and Y 16-bit index registers - enabling indexed addressing modes with or without offset and read-modify-write type data manipulations,
- 8-bit accumulator,
- 24-bit program counter - 16-Mbyte linear memory space,
- 16-bit stack pointer - access to a 64 K-level stack,
- 8-bit condition code register - 7 condition flags for the result of the last instruction.

Addressing

- 20 addressing modes,
- Indexed indirect addressing mode for look-up tables located anywhere in the address space,
- Stack pointer relative addressing mode for local variables and parameter passing.

Instruction set

- 80 instructions with 2-byte average instruction size,
- Standard data movement and logic/arithmetic functions,
- 8-bit by 8-bit multiplication,
- 16-bit by 8-bit and 16-bit by 16-bit division,
- Bit manipulation,
- Data transfer between stack and accumulator (push/pop) with direct stack access,
- Data transfer using the X and Y registers or direct memory-to-memory transfers.

Table 5. STM8S105x4/6 pin description (continued)

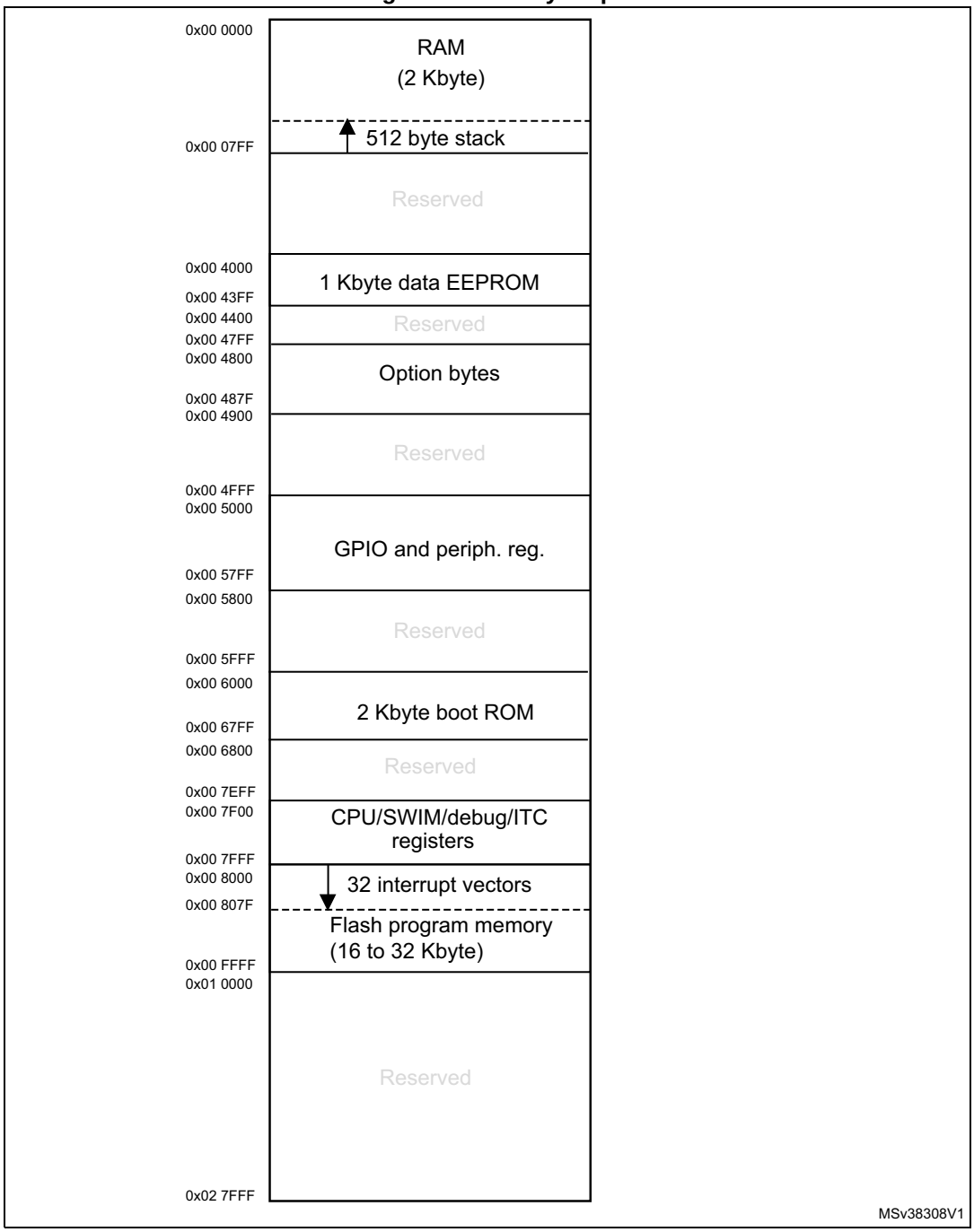
Pin number				Pin name	Type	Input			Output				Main function (after reset)	Default alternate function	Alternate function after remap [option bit]
LQFP48	LQFP44	LQFP32/UFQFPN32	SDIP32			Floating	wpu	Ext. interrupt	High sink	Speed	OD	PP			
40	36	-	-	PE0/ CLK_CCO	I/O	X	X	X	HS	O3	X	X	Port E0	Configurable clock output	-
41	37	25	30	PD0/ TIM3_CH2 [TIM1_BKIN] [CLK_CCO]	I/O	X	X	X	HS	O3	X	X	Port D0	Timer 3 - channel 2	TIM1_BKIN [AFR3]/ CLK_CCO [AFR2]
42	38	26	31	PD1/ SWIM(5)	I/O	X	X	X	X	HS	O4	X	Port D1	SWIM data interface	-
43	39	27	32	PD2/ TIM3_CH1 [TIM2_CH3]	I/O	X	X	X	HS	O3	X	X	Port D2	Timer 3 - channel 1	TIM2_CH3 [AFR1]
44	40	28	1	PD3/ TIM2_CH2 [ADC_ETR]	I/O	X	X	X	HS	O3	X	X	Port D3	Timer 2 - channel 2	ADC_ETR [AFR0]
45	41	29	2	PD4/ TIM2_CH1 [BEEP]	I/O	X	X	X	HS	O3	X	X	Port D4	Timer 2 - channel 1	BEEP output [AFR7]
46	42	30	3	PD5/ UART2_TX	I/O	X	X	X	-	O1	X	X	Port D5	UART2 data transmit	-
47	43	31	4	PD6/ UART2_RX	I/O	X	X	X	-	O1	X	X	Port D6	UART2 data receive	-
48	44	32	5	PD7/ TLI [TIM1_CH4	I/O	X	X	X	-	O1	X	X	Port D7	Top level interrupt	TIM1_CH4 [AFR4]

1. A pull-up is applied to PF4 during the reset phase. This pin is input floating after reset release.
2. AIN12 is not selectable in ADC scan mode or with analog watchdog.
3. In 44-pin package, AIN9 cannot be used by ADC scan mode.
4. In the open-drain output column, 'T' defines a true open-drain I/O (P-buffer, weak pull-up and protection diode to V_{DD} are not implemented).
5. The PD1 pin is in input pull-up during the reset phase and after internal reset release.

6 Memory and register map

6.1 Memory map

Figure 7. Memory map



The following table lists the boundary addresses for each memory size. The top of the stack is at the RAM end address in each case.

Table 6. Flash, data EEPROM and RAM boundary address

Memory area	Size (byte)	Start address	End address
Flash program memory	32 K	0x00 8000	0x00 FFFF
	16 K	0x00 8000	0x00 BFFF
RAM	2 K	0x00 0000	0x00 07FF
Data EEPROM	1024	0x00 4000	0x00 43FF

6.2 Register map

6.2.1 I/O port hardware register map

Table 7. I/O port hardware register map

Address	Block	Register label	Register name	Reset status
0x00 5000	Port A	PA_ODR	Port A data output latch register	0x00
0x00 5001		PA_IDR	Port A input pin value register	0xXX(1)
0x00 5002		PA_DDR	Port A data direction register	0x00
0x00 5003		PA_CR1	Port A control register 1	0x00
0x00 5004		PA_CR2	Port A control register 2	0x00
0x00 5005	Port B	PB_ODR	Port B data output latch register	0x00
0x00 5006		PB_IDR	Port B input pin value register	0xXX(1)
0x00 5007		PB_DDR	Port B data direction register	0x00
0x00 5008		PB_CR1	Port B control register 1	0x00
0x00 5009		PB_CR2	Port B control register 2	0x00
0x00 500A	Port C	PC_ODR	Port C data output latch register	0x00
0x00 500B		PB_IDR	Port C input pin value register	0xXX(1)
0x00 500C		PC_DDR	Port C data direction register	0x00
0x00 500D		PC_CR1	Port C control register 1	0x00
0x00 500E		PC_CR2	Port C control register 2	0x00
0x00 500F	Port D	PD_ODR	Port D data output latch register	0x00
0x00 5010		PD_IDR	Port D input pin value register	0xXX(1)
0x00 5011		PD_DDR	Port D data direction register	0x00
0x00 5012		PD_CR1	Port D control register 1	0x02
0x00 5013		PD_CR2	Port D control register 2	0x00

10 Electrical characteristics

10.1 Parameter conditions

Unless otherwise specified, all voltages are referred to V_{SS}.

10.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at T_A = 25 °C, and T_A = T_{Amax} (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes and are not tested in production. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean ± 3 Σ).

10.1.2 Typical values

Unless otherwise specified, typical data are based on T_A = 25 °C, V_{DD} = 5.0 V. They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated (mean ± 2 Σ).

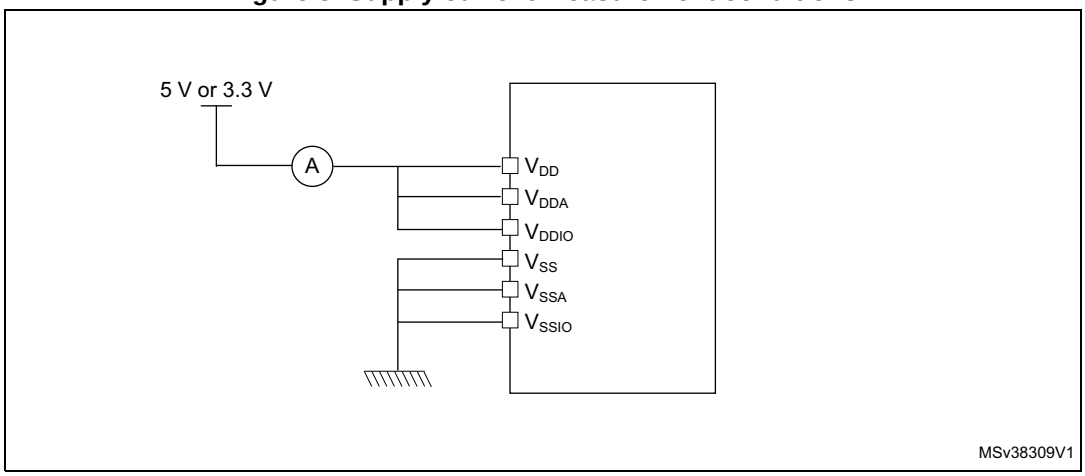
10.1.3 Typical curves

Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

10.1.4 Typical current consumption

For typical current consumption measurements, VDD, VDDIO and VDDA are connected together in the configuration shown in the following figure.

Figure 8. Supply current measurement conditions



10.2 Absolute maximum ratings

Stresses above those listed as 'absolute maximum ratings' may cause permanent damage to the device. This is a stress rating only and functional operation of the device under these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 15. Voltage characteristics

Symbol	Ratings	Min	Max	Unit
V_{DDx} - V_{SS}	Supply voltage (including V_{DDA} and V_{DDIO})(1)	-0.3	6.5	V
V_{IN}	Input voltage on true open drain pins (PE1, PE2)(2)	V_{SS} - 0.3	6.5	V
	Input voltage on any other pin(2)	V_{SS} - 0.3	V_{DD} + 0.3	
$\lvert V_{DDx} - V_{DD} \rvert$	Variations between different power pins	-	50	mV
$\lvert V_{SSx} - V_{SS} \rvert$	Variations between all the different ground pins	-	50	
V_{ESD}	Electrostatic discharge voltage	see *Absolute maximum ratings (electrical sensitivity) on page 89*		

1. All power (V_{DD}) and ground (V_{SS}) pins must always be connected to the external power supply
2. $I_{INJ(PIN)}$ must never be exceeded. This is implicitly insured if V_{IN} maximum is respected. If V_{IN} maximum cannot be respected, the injection current must be limited externally to the $I_{INJ(PIN)}$ value. A positive injection is induced by $V_{IN} > V_{DD}$ while a negative injection is induced by $V_{IN} < V_{SS}$. For true open-drain pads, there is no positive injection current, and the corresponding V_{IN} maximum must always be respected

Table 16. Current characteristics

Symbol	Ratings	Max.(1)	Unit
I_{VDD}	Total current into V_{DD} power lines (source)(2)	100	mA
I_{VSS}	Total current out of V_{SS} ground lines (sink)(1)	80	
I_{IO}	Output current sunk by any I/O and control pin	20	
	Output current source by any I/Os and control pin	-20	
ΣI_{IO}	Total output current sourced (sum of all I/O and control pins) for devices with two V_{DDIO} pins(3)	200	
	Total output current sourced (sum of all I/O and control pins) for devices with one V_{DDIO} pin(3)	100	
	Total output current sunk (sum of all I/O and control pins) for devices with two V_{SSIO} pins(3)	160	
	Total output current sunk (sum of all I/O and control pins) for devices with one V_{SSIO} pin(3)	80	
$I_{INJ(PIN)}$ (4) (5)	Injected current on NRST pin	±4	
	Injected current on OSCIN pin	±4	
	Injected current on any other pin(6)	±4	
$\Sigma I_{INJ(PIN)}$(4)	Total injected current (sum of all I/O and control pins)(6)	±20	

1. Data based on characterization results, not tested in production.
2. All power (V_{DD}, V_{DDIO}, V_{DDA}) and ground (V_{SS}, V_{SSIO}, V_{SSA}) pins must always be connected to the external supply.

Table 19. Operating conditions at power-up/power-down (continued)

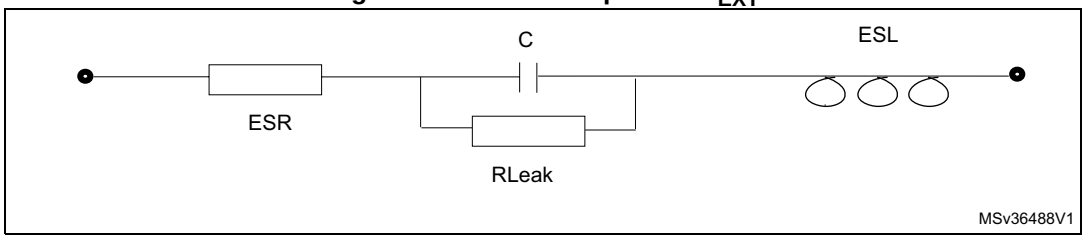
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{IT+}	Power-on reset threshold	-	2.65	2.8	2.95	V
V_{IT-}	Brown-out reset threshold	-	2.58	2.65	2.88	
$V_{HYS(BOR)}$	Brown-out reset hysteresis	-	-	70	-	mV

1. Guaranteed by design, not tested in production.

10.3.1 VCAP external capacitor

The stabilization for the main regulator is achieved by connecting an external capacitor C_{EXT} to the V_{CAP} pin. C_{EXT} is specified in *Table 18*. Care should be taken to limit the series inductance to less than 15 nH.

Figure 12. External capacitor C_{EXT}



1. ESR is the equivalent series resistance and ESL is the equivalent inductance.

10.3.2 Supply current characteristics

The current consumption is measured as illustrated in *Figure 10: Pin input voltage*.

Total current consumption in run mode

Table 20. Total current consumption with code execution in run mode at V_{DD} = 5 V

Symbol	Parameter	Conditions		Typ	Max(1)	Unit
$I_{DD(RUN)}$	Supply current in Run mode, code executed from RAM	$f_{CPU} = f_{MASTER}$ = 16 MHz	HSE crystal osc. (16 MHz)	3.2	-	mA
			HSE user ext. clock (16 MHz)	2.6	3.2	
			HSI RC osc. (16 MHz)	2.5	3.2	
		$f_{CPU} = f_{MASTER}$ /128 = 125 kHz	HSE user ext. clock (16 MHz)	1.6	2.2	
			HSI RC osc. (16 MHz)	1.3	2.0	
		$f_{CPU} = f_{MASTER}$ /128 = 15.625 kHz	HSI RC osc. (16 MHz/8)	0.75	-	
		$f_{CPU} = f_{MASTER}$ = 128 kHz	LSI RC osc. (128 kHz)	0.55	-	
$I_{DD(RUN)}$	Supply current in Run mode, code executed from Flash	$f_{CPU} = f_{MASTER}$ = 16 MHz	HSE crystal osc. (16 MHz)	7.7	-	mA
			HSE user ext. clock (16 MHz)	7.0	8.0	
			HSI RC osc. (16 MHz)	7.0	8.0	
		$f_{CPU} = f_{MASTER}$ = 2 MHz	HSI RC osc. (16 MHz/8)(2)	1.5	-	
		$f_{CPU} = f_{MASTER}$ /128 = 125 kHz	HSI RC osc. (16 MHz)	1.35	2.0	
		$f_{CPU} = f_{MASTER}$ /128 = 15.625 kHz	HSI RC osc. (16 MHz/8)	0.75	-	
		$f_{CPU} = f_{MASTER}$ = 128 kHz	LSI RC osc. (128 kHz)	0.6	-	

1. Data based on characterization results, not tested in production.
2. Default clock configuration measured with all peripherals off.

10.3.3 External clock sources and timing characteristics

HSE user external clock

Subject to general operating conditions for V_{DD} and T_A.

Table 31. HSE user external clock characteristics

Symbol	Parameter	Conditions	Min	Max	Unit
f_{HSE_ext}	User external clock source frequency	-	0	16	MHz
V_{HSEH}(1)	OSCIN input pin high level voltage	-	0.7 x V_{DD}	V_{DD} + 0.3 V	V
V_{HSEL}(1)	OSCIN input pin low level voltage	-	V_{SS}	0.3 x V_{DD}	
I_{LEAK_HSE}	OSCIN input leakage current	$V_{SS} < V_{IN} < V_{DD}$	-1	+1	µA

1. Data based on characterization results, not tested in production.

Figure 19. HSE external clock source

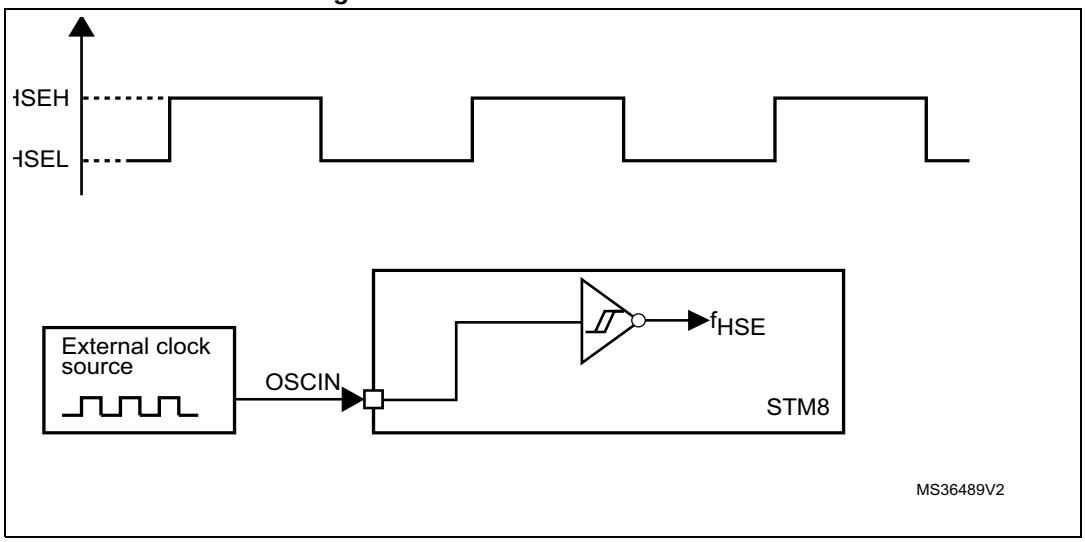


Figure 22. Typical HSI frequency variation vs V_{DD} @ 4 temperatures

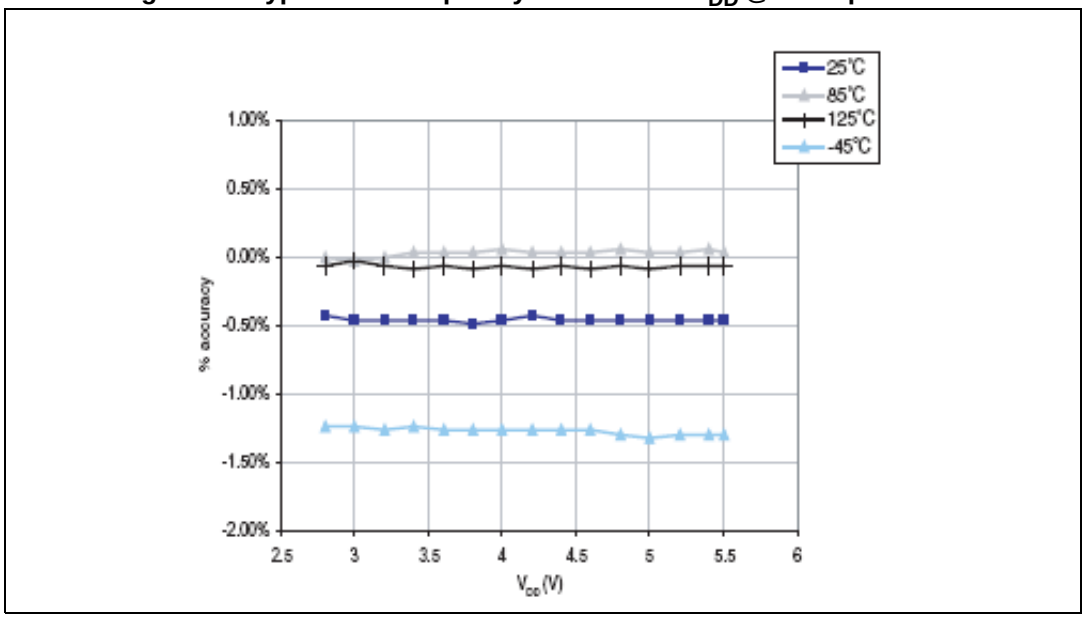


Table 39. Output driving current (true open drain ports)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{OL}	Output low level with 2 pins sunk	I_{IO}= 10 mA, V_{DD} = 5 V	-	1.0	V
	Output low level with 2 pins sunk	I_{IO}= 10 mA, V_{DD} = 3.3 V	-	1.5(1)	
V_{OH}	Output high level with 2 pins sourced	I_{IO}= 10 mA, V_{DD} = 5 V	-	2.0(1)	

1. Data based on characterization results, not tested in production

Table 40. Output driving current (high sink ports)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{OL}	Output low level with 8 pins sunk	I_{IO}= 10 mA, V_{DD} = 5 V	-	0.9	V
	Output low level with 4 pins sunk	I_{IO}= 10 mA, V_{DD} = 3.3 V	-	1.1(1)	
		I_{IO}= 20 mA, V_{DD} = 5 V	-	1.6(1)	
V_{OH}	Output high level with 8 pins sourced	I_{IO}= 10 mA, V_{DD} = 5 V	3.8	-	
	Output high level with 4 pins sourced	I_{IO}= 10 mA, V_{DD} = 3.3 V	1.9(1)	-	
		I_{IO}= 20 mA, V_{DD} = 5 V	2.9(1)	-	

1. Data based on characterization results, not tested in production.

10.3.7 Typical output level curves

The following figures show the typical output level curves measured with the output on a single pin.

Figure 27. Typ. V_{OL} @ V_{DD} = 3.3 V (standard ports)

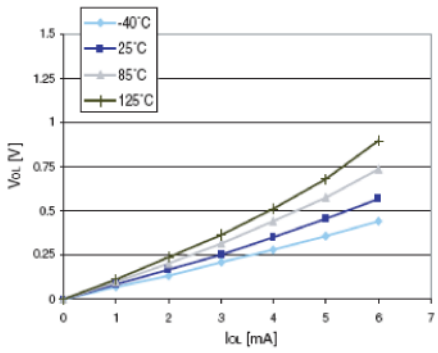
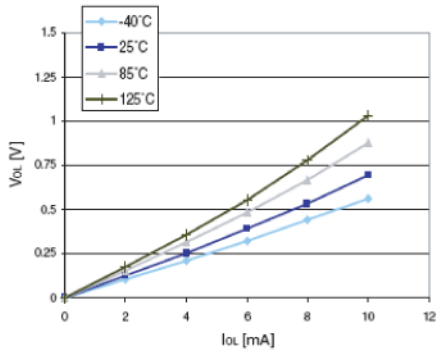


Figure 28. Typ. V_{OL} @ V_{DD} = 5.0 V (standard ports)



1. Data obtained with HSI clock configuration, after applying the hardware recommendations described in AN2860 (EMC guidelines for STM8S microcontrollers).

Electromagnetic interference (EMI)

Based on a simple application running on the product (toggling 2 LEDs through the I/O ports), the product is monitored in terms of emission. This emission test is in line with the norm IEC 61967-2 which specifies the board and the loading of each pin.

Table 48. EMI data

Symbol	Parameter	Conditions				Unit
		General conditions	Monitored frequency band	Max f_{HSE}/f_{CPU}(1)		
				8 MHz/ 8 MHz	8 MHz/ 16 MHz	
S_{EMI}	Peak level	V_{DD} = 5 V, T_A = 25 °C, LQFP48 package. Conforming to IEC 61967-2	0.1 MHz to 30 MHz	13	14	dBµV
			30 MHz to 130 MHz	23	19	
			130 MHz to 1 GHz	-4.0	-4.0	
	EMI level		EMI level	2.0	1.5	-

1. Data based on characterization results, not tested in production.

Absolute maximum ratings (electrical sensitivity)

Based on two different tests (ESD, DLU and LU) using specific measurement methods, the product is stressed to determine its performance in terms of electrical sensitivity. For more details, refer to the application note AN1181.

Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts x (n+1) supply pin). One model can be simulated: Human body model. This test conforms to the JESD22-A114A/A115A standard. For more details, refer to the application note AN1181.

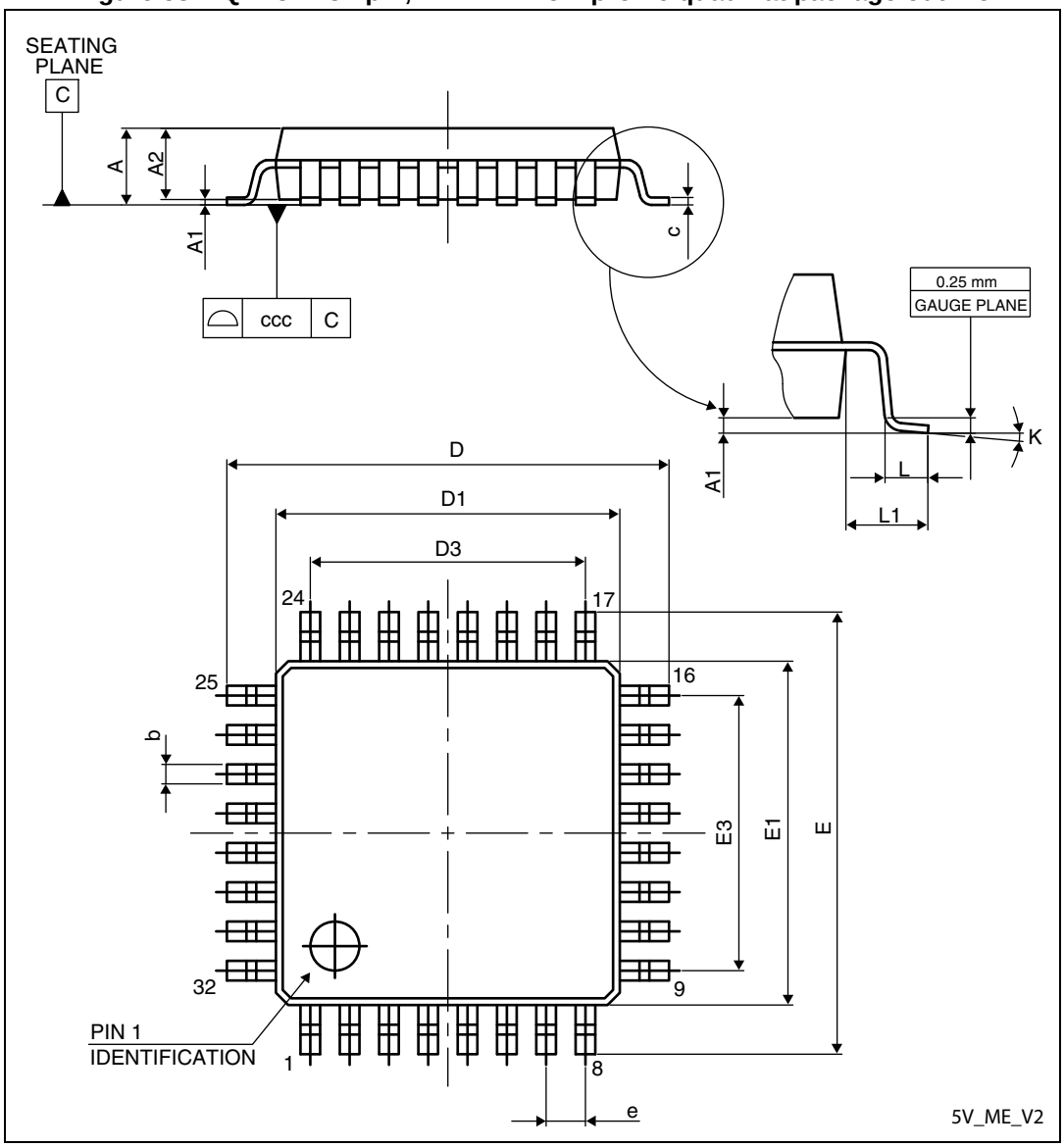
Table 49. ESD absolute maximum ratings

Symbol	Ratings	Conditions	Class	Maximum value(1)	Unit
$V_{ESD(HBM)}$	Electrostatic discharge voltage (Human body model)	T_A = 25°C, conforming to JESD22-A114	A	2000	V
$V_{ESD(CDM)}$	Electrostatic discharge voltage (Charge device model)	T_A= 25°C, conforming to SD22-C101	IV	1000	

1. Data based on characterization results, not tested in production

11.3 LQFP32 package information

Figure 53. LQFP32 - 32-pin, 7 x 7 mm low-profile quad flat package outline



1. Drawing is not to scale.

11.5 SDIP32 package information

Figure 59. SDIP32 package outline

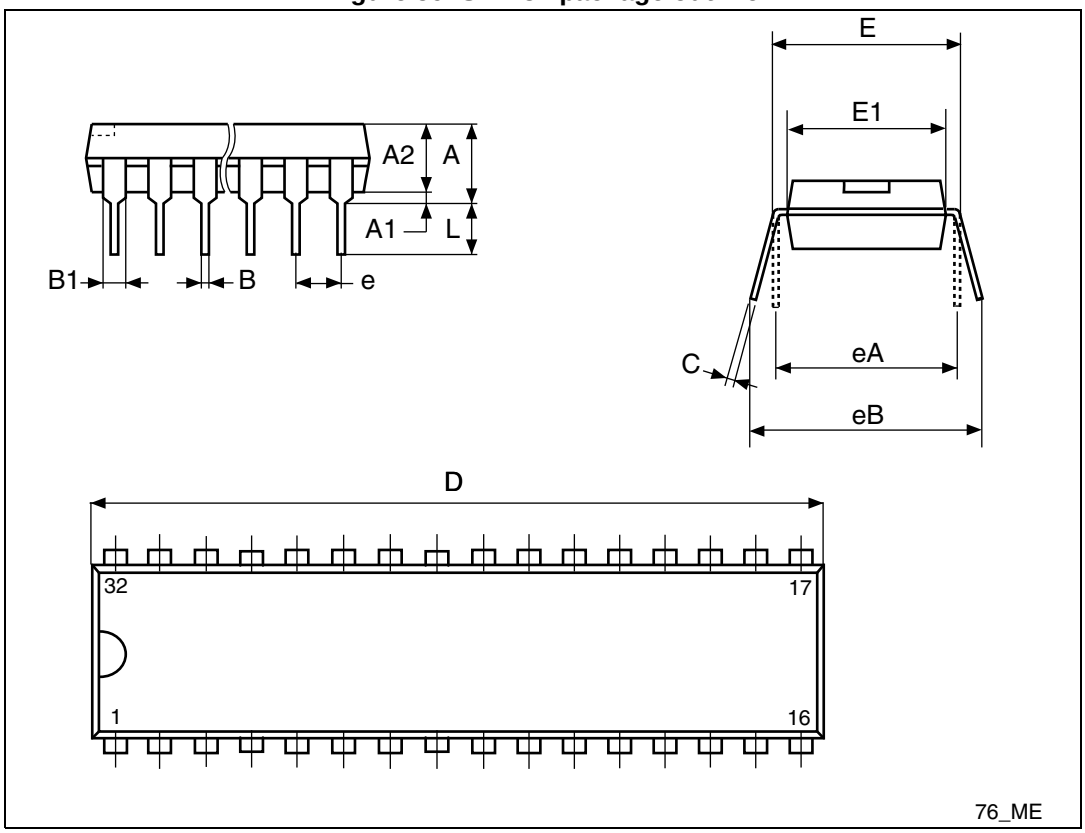


Table 55. SDIP32 package mechanical data

Dim.	mm			inches[1]		
	Min	Typ	Max	Min	Typ	Max
A	3.556	3.759	5.080	0.1400	0.1480	0.2000
A1	0.508	-	-	0.0200	-	-
A2	3.048	3.556	4.572	0.1200	0.1400	0.1800
B	0.356	0.457	0.584	0.0140	0.0180	0.0230
B1	0.762	1.016	1.397	0.0300	0.0400	0.0550
C	0.203	0.254	0.356	0.0079	0.0100	0.0140
D	27.430	27.940	28.450	1.0799	1.1000	1.1201
E	9.906	10.410	11.050	0.3900	0.4098	0.4350
E1	7.620	8.890	9.398	0.3000	0.3500	0.3700
e	-	1.778	-	-	0.0700	-
eA	-	10.160	-	-	0.4000	-

Table 55. SDIP32 package mechanical data (continued)

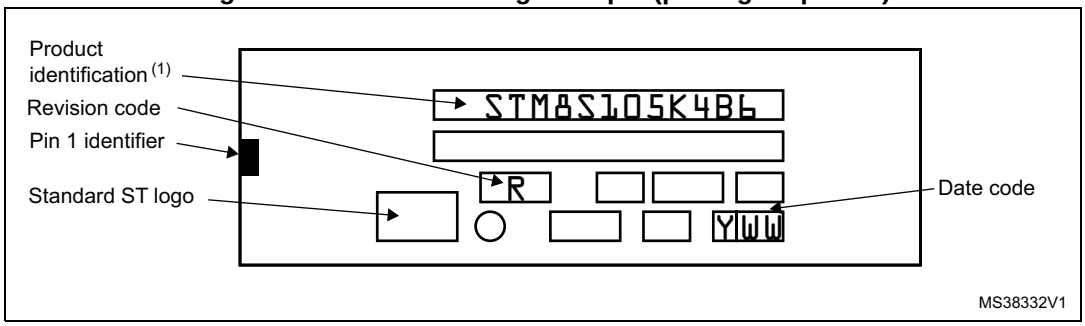
Dim.	mm			inches[1]		
	Min	Typ	Max	Min	Typ	Max
eB	-	-	12.700	-	-	0.5000
L	2.540	3.048	3.810	0.1000	0.1200	0.1500

1. Values in inches are converted from mm and rounded to 4 decimal digits

Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

Figure 60. SDIP32 marking example (package top view)



1. Parts marked as “ES”,”E” or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

12 Thermal characteristics

The maximum junction temperature (T_{Jmax}) of the device must never exceed the values specified in *Table 18: General operating conditions*, otherwise the functionality of the device cannot be guaranteed.

The maximum junction temperature T_{Jmax}, in degrees Celsius, may be calculated using the following equation:

$$T_{Jmax} = T_{Amax} + (P_{Dmax} \times \Theta_{JA})$$

Where:

- T_{Amax} is the maximum ambient temperature in °C
- Θ_{JA} is the package junction-to-ambient thermal resistance in ° C/W
- P_{Dmax} is the sum of P_{INTmax} and $P_{I/Omax}$ ($P_{Dmax} = P_{INTmax} + P_{I/Omax}$)
- P_{INTmax} is the product of I_{DD} and V_{DD}, expressed in Watts. This is the maximum chip internal power.
- $P_{I/Omax}$ represents the maximum power dissipation on output pins
  Where:
  $P_{I/Omax} = \Sigma (V_{OL}*I_{OL}) + \Sigma((V_{DD}-V_{OH})*I_{OH})$,
  taking into account the actual V_{OL}/I_{OL} and V_{OH}/I_{OH} of the I/Os at low and high level in the application.

Table 56. Thermal characteristics(1)

Symbol	Parameter	Value	Unit
Θ_{JA}	Thermal resistance junction-ambient LQFP48 - 7x7 mm		°C/W
	Thermal resistance junction-ambient LQFP44 - 10x10 mm		
	Thermal resistance junction-ambient LQFP32 - 7x7 mm		
	Thermal resistance junction-ambient UFQFPN32 - 5x5 mm		
	Thermal resistance junction-ambient SDIP32 - 400 ml		

1. Thermal resistances are based on JEDEC JESD51-2 with 4-layer PCB in a natural convection environment.

12.1 Reference document

JESD51-2 integrated circuits thermal test method environment conditions - natural convection (still air). Available from www.jedec.org.

Padding value for unused program memory (check only one option)

[ ] 0xFF	Fixed value
[ ] 0x83	TRAP instruction code
[ ] 0x75	Illegal opcode (causes a reset when executed)

OTP0 memory readout protection (check only one option)

[ ] Disable or [ ] Enable

OTP1 user boot code area (UBC)

0x(_ _) fill in the hexadecimal value, referring to the datasheet and the binary format below:

UBC, bit0	[ ] 0: Reset [ ] 1: Set
UBC, bit1	[ ] 0: Reset [ ] 1: Set
UBC, bit2	[ ] 0: Reset [ ] 1: Set
UBC, bit3	[ ] 0: Reset [ ] 1: Set
UBC, bit4	[ ] 0: Reset [ ] 1: Set
UBC, bit5	[ ] 0: Reset [ ] 1: Set

OTP2 alternate function remapping

AFR0 (check only one option)	[ ] 0: Remapping option inactive. Default alternate functions used. Refer to pinout description [ ] 1: Port D3 alternate function = ADC_ETR
AFR1 (check only one option)	[ ] 0: Remapping option inactive. Default alternate functions used. Refer to pinout description [ ] 1: Port A3 alternate function = TIM3_CH1, port D2 alternate function = TIM2_CH3
AFR2 (check only one option)	[ ] 0: Remapping option inactive. Default alternate functions used. Refer to pinout description [ ] 1: Port D0 alternate function = CLK_CCO *Note: if both AFR2 and AFR3 are activated, AFR2 option has priority over AFR3.*
AFR3 (check only one option)	[ ] 0: Remapping option inactive. Default alternate functions used. Refer to pinout description [ ] 1: Port D0 alternate function = TIM1_BKIN

OPT5 crystal oscillator stabilization HSECNT (check only one option)

[ ] 2048 HSE cycles

[ ] 128 HSE cycles

[ ] 8 HSE cycles

[ ] 0.5 HSE cycles

OTP6 is reserved

OTP7 is reserved

OTPBL bootloader option byte (check only one option)

Refer to the UM0560 (STM8L/S bootloader manual) for more details.

[ ] Disable (00h)

[ ] Enable (55h)

Comments:	.....
Supply operating range in the application:	.....
Notes:	.....
Date:	.....
Signature:	.....